# $28 V$ Internal Switch LCD Bias Supply with True Shutdown 

## General Description

The MAX1606 is a step-up DC-DC converter that contains a 0.5 A internal power switch and a 0.5 A output isolation switch in an 8 -pin $\mu \mathrm{MAX}$ package. The IC operates from a 2.4 V to 5.5 V supply voltage but can boost battery voltages as low as 0.8 V up to 28 V .
The MAX1606 uses a unique control scheme that provides high efficiency over a wide range of load conditions. An internal 0.5A MOSFET reduces external component count, and a high switching frequency (up to 500 kHz ) allows for tiny surface-mount components. The current limit can be set to $500 \mathrm{~mA}, 250 \mathrm{~mA}$, or 125 mA , allowing the user to reduce the output ripple and component size in low-current applications.
Additional features include a low quiescent supply current and a true shutdown mode that saves power by disconnecting the output from the input. The MAX1606 is ideal for small LCD panels with low current requirements but can also be used in other applications. A MAX1606 evaluation kit is available to help speed up design time.

Applications
LCD Bias Generators
Cellular or Cordless Phones
Palmtop Computers
Personal Digital Assistants (PDAs)
Organizers
Handy Terminals

Typical Operating Circuit


Features

- Adjustable Output Voltage up to 28V
- 20mA at 20V from a Single Li+ Battery
- True Shutdown (Output Disconnected from Input)
- Output Short-Circuit Protection
- 88\% Efficiency
- Up to 500kHz Switching Frequency
- Selectable Inductor Current Limit ( $125 \mathrm{~mA}, 250 \mathrm{~mA}$, or 500 mA )
- $0.1 \mu \mathrm{~A}$ Shutdown Current
- 8-Pin $\mu$ MAX Package

Ordering Information

| PART | TEMP RANGE | PIN-PACKAGE |
| :---: | :--- | :--- |
| MAX1606EUA | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | $8 \mu \mathrm{MAX}$ |

Pin Configuration


## 28V Internal Switch LCD Bias Supply with True Shutdown

## ABSOLUTE MAXIMUM RATINGS

| $\mathrm{V}_{\mathrm{CC}}, \mathrm{FB}, \mathrm{BATT}$, SW to GND | -0.3V to +6V |
| :---: | :---: |
| BATT to SW | -0.3V to +6V |
| SHDN, LIM to GND. | .-0.3V to ( $\left.\mathrm{V}_{C C}+0.3 \mathrm{~V}\right)$ |
| LX to GND | .........-0.3V to +30V |
| Current into LX or BATT | .600mARMS |
| Current out of SW | .600mARMS |
| Output Short-Circuit Duration | . Indefinite |


| Continuous Power Dissipation ( $\left.\mathrm{T}_{\mathrm{A}}=+70^{\circ} \mathrm{C}\right)$ |  |
| :---: | :---: |
| 8 -Pin $\mu \mathrm{MAX}$ (derate $4.1 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $+70^{\circ} \mathrm{C}$ ). | 330 mW |
| Operating Temperature Range ......................... $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |  |
| Junction Temperature | $+150^{\circ} \mathrm{C}$ |
| Storage Temperature Range ..........................-6 | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Lead Temperature (soldering, 10s) | $+300^{\circ} \mathrm{C}$ |

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ELECTRICAL CHARACTERISTICS

$\left(\mathrm{V}_{C C}=3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{CC}}=\mathrm{BATT}=\overline{\mathrm{SHDN}}, \mathbf{T}_{\mathbf{A}}=\mathbf{0}^{\circ} \mathbf{C}\right.$ to $+\mathbf{8 5}{ }^{\circ} \mathbf{C}$, unless otherwise noted. Typical values are at $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$.)

| PARAMETER | SYMBOL | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| VCC Supply Voltage | $V_{C C}$ | (Note 1) | 2.4 |  | 5.5 | V |
| BATT Input Voltage Range | VBATT | (Note 1) | 0.8 |  | 5.5 | V |
| VCC Undervoltage Lockout | VUVLO | $V_{C C}$ falling, 30mV typical hysteresis | 2.0 | 2.2 | 2.37 | V |
| VCC Quiescent Supply Current | IcC | $V_{\text {FB }}=1.3 \mathrm{~V}$ |  | 160 | 320 | $\mu \mathrm{A}$ |
| VCC Shutdown Supply Current |  | $\overline{\text { SHDN }}=$ GND |  | 0.1 | 1 | $\mu \mathrm{A}$ |
| BATT Input Supply Current | IBATT | $\mathrm{V}_{\mathrm{FB}}=1.3 \mathrm{~V}$ |  | 20 | 40 | $\mu \mathrm{A}$ |
| BATT Shutdown Supply Current |  | $\overline{\text { SHDN }}=$ GND |  | 0.1 | 1 | $\mu \mathrm{A}$ |
| VCC Line Regulation | $\Delta \mathrm{V}_{\text {LNR }}$ | $\begin{aligned} & \mathrm{V}_{\text {OUT }}=18 \mathrm{~V}, \operatorname{ILOAD}=1 \mathrm{~mA}, \mathrm{~V}_{\text {BATT }}=3.6 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{CC}}=\mathrm{V}_{\text {LIM }}=2.4 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \end{aligned}$ |  | 0.1 |  | \%/V |
| BATT Line Regulation | $\Delta \mathrm{V}_{\text {LNR }}$ | $\begin{aligned} & \text { VOUT }=18 \mathrm{~V}, \operatorname{LOAD}=1 \mathrm{~mA}, \\ & \mathrm{~V}_{\mathrm{CC}}=\mathrm{V}_{\text {LIM }}=3.3 \mathrm{~V}, \mathrm{~V}_{\text {BATT }}=0.8 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \end{aligned}$ |  | 0.05 |  | \%/V |
| Load Regulation | $\Delta \mathrm{V}_{\text {LDR }}$ | $\begin{aligned} & \mathrm{V}_{\text {OUT }}=18 \mathrm{~V}, \mathrm{~V}_{\mathrm{CC}}=\mathrm{V}_{\text {BATT }}=\mathrm{V}_{\mathrm{LIM}}=3.3 \mathrm{~V}, \\ & \mathrm{I}_{\text {LOAD }}=0 \mathrm{~mA} \text { to } 20 \mathrm{~mA} \end{aligned}$ |  | 0.05 |  | \%/mA |
| Efficiency |  | $\mathrm{L} 1=100 \mu \mathrm{H}, \mathrm{V}_{\text {BATT }}=3.6 \mathrm{~V}, \mathrm{~L}$ LOAD $=10 \mathrm{~mA}$ |  | 88 |  | \% |
| Feedback Set Point | $V_{\text {FB }}$ |  | 1.225 | 1.25 | 1.275 | V |
| Feedback Input Bias Current | IFB | $V_{F B}=1.3 \mathrm{~V}$ |  | 5 | 100 | nA |
| INDUCTOR CONNECTIONS (LX, SW) |  |  |  |  |  |  |
| LX Voltage Range | VLX |  |  |  | 28 | V |
| LX Switch Current Limit | ILX(MAX) | LIM = VCC | 0.40 | 0.50 | 0.56 | A |
|  |  | LIM = floating | 0.20 | 0.25 | 0.285 |  |
|  |  | LIM = GND | 0.10 | 0.125 | 0.15 |  |
| LX On-Resistance | RLX | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{ILX}=100 \mathrm{~mA}$ |  | 0.8 |  | $\Omega$ |
|  |  | $\mathrm{VCC}=3.3 \mathrm{~V}, \mathrm{l} \mathrm{LX}=100 \mathrm{~mA}$ |  | 1 | 2 |  |
| LX Leakage Current |  | $V_{L X}=28 \mathrm{~V}$ |  |  | 2 | $\mu \mathrm{A}$ |
| Maximum LX On-Time | ton |  | 10 | 13 | 16 | $\mu \mathrm{s}$ |
| Minimum LX Off-Time | tOFF | $\mathrm{V}_{\mathrm{FB}}>1.1 \mathrm{~V}$ | 0.8 | 1.0 | 1.2 | $\mu \mathrm{s}$ |
|  |  | $\mathrm{V}_{\text {FB }}<0.8 \mathrm{~V}$ (soft-start) | 3.9 | 5.0 | 6.0 |  |
| SW Leakage Current |  | $\mathrm{SW}=\mathrm{GND}, \mathrm{V}_{\text {BATT }}=5.5 \mathrm{~V}$ |  |  | 1 | $\mu \mathrm{A}$ |

## $28 V$ Internal Switch LCD Bias Supply with True Shutdown

## ELECTRICAL CHARACTERISTICS (continued)

$\left(\mathrm{V} C \mathrm{C}=3.3 \mathrm{~V}, \mathrm{~V}_{C C}=\mathrm{BATT}=\overline{\mathrm{SHDN}}, \mathbf{T}_{\mathbf{A}}=\mathbf{0}^{\circ} \mathbf{C}\right.$ to $+\mathbf{8 5}{ }^{\circ} \mathbf{C}$, unless otherwise noted. Typical values are at $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$.)

| PARAMETER | SYMBOL | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CONTROL INPUTS ( $\overline{\text { SHDN, LIM) }}$ |  |  |  |  |  |  |
| $\overline{\text { SHDN }}$ Input Threshold | $\mathrm{V}_{\mathrm{IH}}$ | $2.4 \mathrm{~V} \leq \mathrm{V}_{\mathrm{CC}} \leq 5.5 \mathrm{~V}$ | $\begin{aligned} & 0.8 \times \\ & V_{C C} \end{aligned}$ |  |  | V |
|  | VIL | $2.4 \mathrm{~V} \leq \mathrm{V}_{\mathrm{CC}} \leq 5.5 \mathrm{~V}$ |  |  | $\begin{aligned} & 0.2 \times \\ & V_{C C} \end{aligned}$ |  |
| $\overline{\text { SHDN }}$ Input Bias Current | ISHDN | $\mathrm{V}_{C C}=5.5 \mathrm{~V}, \mathrm{~V} \overline{\text { SHDN }}=0$ to 5.5 V | -1 |  | +1 | $\mu \mathrm{A}$ |
| LIM Input Low Level |  | $2.4 \mathrm{~V} \leq \mathrm{V}_{\mathrm{CC}} \leq 5.5 \mathrm{~V}$ |  |  | 0.4 | V |
| LIM Input Float Level |  | $\begin{aligned} & 2.4 \mathrm{~V} \leq \mathrm{V} \mathrm{CC} \leq 5.5 \mathrm{~V}, \\ & \mathrm{I} \text { LIM }= \pm 0.5 \mu \mathrm{~A} \end{aligned}$ | $\left\lvert\, \begin{aligned} & \left(V_{C C} / 2\right) \\ & -0.25 \mathrm{~V} \end{aligned}\right.$ |  | $\begin{gathered} \left(V_{C C} / 2\right) \\ +0.25 \mathrm{~V} \end{gathered}$ | V |
| LIM Input High Level |  | $2.4 \mathrm{~V} \leq \mathrm{V}_{\mathrm{CC}} \leq 5.5 \mathrm{~V}$ | $\begin{gathered} \mathrm{VCC}_{C C} \\ -0.4 \mathrm{~V} \end{gathered}$ |  |  | V |
| LIM Input Bias Current | ILIM | $\overline{\mathrm{SHDN}}=\mathrm{V}_{C C}, \mathrm{LIM}=\mathrm{GND}$ or $\mathrm{V}_{C C}$ | -2 |  | +2 | $\mu \mathrm{A}$ |
|  |  | $\overline{\text { SHDN }}=$ GND |  | 0.1 | 1 |  |
| PMOS ISOLATION SWITCH (BATT to SW) |  |  |  |  |  |  |
| PMOS Current Limit |  | $\mathrm{V}_{C C}=2.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{BAT}}=1.5 \mathrm{~V}$ | 0.6 | 0.75 | 1.5 | A |
| PMOS On-Resistance | RDS(ON) | $\mathrm{V}_{C C}=2.5 \mathrm{~V}, \mathrm{~V}_{\text {BATT }}=1.5 \mathrm{~V}, \mathrm{ISW}=100 \mathrm{~mA}$ |  | 0.25 | 0.4 | $\Omega$ |
| Soft-Start Time | tss | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=2.5 \mathrm{~V}, \mathrm{~V}_{\text {BATT }}=1.5 \mathrm{~V}, \\ & \mathrm{RSW}=50 \Omega \text { to } \mathrm{GND} \end{aligned}$ |  | 0.3 |  | ms |

## ELECTRICAL CHARACTERISTICS

( $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{CC}}=\mathrm{BATT}=\overline{\mathrm{SHDN}}, \mathbf{T}_{\mathbf{A}}=\mathbf{- 4 0 ^ { \circ }} \mathbf{C}$ to $\mathbf{+ 8 5}^{\circ} \mathbf{C}$, unless otherwise noted.) (Note 2)

| PARAMETER | SYMBOL | CONDITIONS | MIN | TYP MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| VCC Supply Voltage | $V_{C C}$ | (Note 1) | 2.4 | 5.5 | V |
| BATT Input Voltage Range | $V_{\text {BATT }}$ | (Note 1) | 0.8 | VOUT | V |
| $V_{\text {CC }}$ Undervoltage Lockout | VUVLO | $V_{C C}$ falling, 30mV typical hysteresis | 2.00 | 2.37 | V |
| VCC Quiescent Supply Current | ICC | $V_{F B}=1.3 \mathrm{~V}$ |  | 360 | $\mu \mathrm{A}$ |
| VCC Shutdown Supply Current |  | $\overline{\text { SHDN }}=\mathrm{GND}$ |  | 1 | $\mu \mathrm{A}$ |
| BATT Input Supply Current | IBATT | $\mathrm{V}_{\mathrm{FB}}=1.3 \mathrm{~V}$ |  | 40 | $\mu \mathrm{A}$ |
| BATT Shutdown Supply Current |  | $\overline{\mathrm{SHDN}}=\mathrm{GND}$ |  | 1 | $\mu \mathrm{A}$ |
| Feedback Set Point | $V_{\text {FB }}$ |  | 1.215 | 1.285 | V |
| Feedback Input Bias Current | IFB | $V_{F B}=1.3 \mathrm{~V}$ |  | 100 | nA |
| INDUCTOR CONNECTIONS (LX, SW) |  |  |  |  |  |
| LX Voltage Range | VLX |  |  | 28 | V |
| LX Switch Current Limit | ILX(MAX) | LIM $=\mathrm{V}_{\text {CC }}$ | 0.35 | 0.58 | A |
|  |  | LIM = floating | 0.18 | 0.30 |  |
|  |  | LIM = GND | 0.08 | 0.17 |  |
| LX On-Resistance | RLX | $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}, \mathrm{ILX}=100 \mathrm{~mA}$ |  | 2 | $\Omega$ |
| LX Leakage Current |  | $V_{L X}=28 \mathrm{~V}$ |  | 2 | $\mu \mathrm{A}$ |
| Maximum LX On-Time | ton |  | 9 | 17 | $\mu \mathrm{s}$ |

## 28V Internal Switch LCD Bias Supply with True Shutdown

## ELECTRICAL CHARACTERISTICS (continued)

$\left(\mathrm{V}_{C C}=3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{CC}}=\mathrm{BATT}=\overline{\mathrm{SHDN}}, \mathbf{T}_{\mathbf{A}}=\mathbf{- 4 0 ^ { \circ }} \mathbf{C}\right.$ to $\mathbf{+ 8 5}{ }^{\circ} \mathbf{C}$, unless otherwise noted.) (Note 2)

| PARAMETER | SYMBOL | CONDITIONS | MIN | TYP MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Minimum LX Off-Time | toff | $\mathrm{V}_{\mathrm{FB}}>1.1 \mathrm{~V}$ | 0.75 | 1.25 | $\mu \mathrm{s}$ |
|  |  | $\mathrm{V}_{\mathrm{FB}}<0.8 \mathrm{~V}$ (soft-start) | 3.8 | 6.0 |  |
| SW Leakage Current |  | $\mathrm{SW}=\mathrm{GND}, \mathrm{V}_{\text {BATT }}=5.5 \mathrm{~V}$ |  | 1 | $\mu \mathrm{A}$ |
| CONTROL INPUTS ( $\overline{\text { SHDN, LIM) }}$ |  |  |  |  |  |
| $\overline{\text { SHDN }}$ Input Threshold | $\mathrm{V}_{\mathrm{IH}}$ | $2.4 \mathrm{~V} \leq \mathrm{V}_{\mathrm{CC}} \leq 5.5 \mathrm{~V}$ | $\begin{aligned} & 0.8 \times \\ & V_{C C} \end{aligned}$ |  | V |
|  | VIL | $2.4 \mathrm{~V} \leq \mathrm{V}_{\mathrm{CC}} \leq 5.5 \mathrm{~V}$ |  | $\begin{aligned} & 0.2 \times \\ & V_{C C} \end{aligned}$ |  |
| $\overline{\text { SHDN }}$ Input Bias Current | ISHDN | $\mathrm{V}_{C C}=5.5 \mathrm{~V}, \mathrm{~V} \overline{\text { SHDN }}=0$ to 5.5 V | -1 | +1 | $\mu \mathrm{A}$ |
| LIM Input Low Level |  | $2.4 \mathrm{~V} \leq \mathrm{V}_{\mathrm{CC}} \leq 5.5 \mathrm{~V}$ |  | 0.4 | V |
| LIM Input Float Level |  | $\begin{aligned} & 2.4 \mathrm{~V} \leq \mathrm{V}_{\mathrm{CC}} \leq 5.5 \mathrm{~V} \\ & \mathrm{ILM}= \pm 0.5 \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & \left(\mathrm{V}_{\mathrm{CC}} / 2\right) \\ & -0.25 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \left(V_{C C} / 2\right) \\ & +0.25 \mathrm{~V} \end{aligned}$ | V |
| LIM Input High Level |  | $2.4 \mathrm{~V} \leq \mathrm{V}_{\mathrm{CC}} \leq 5.5 \mathrm{~V}$ | $\begin{gathered} \mathrm{V}_{\mathrm{CC}} \\ -0.4 \mathrm{~V} \end{gathered}$ |  | V |
| LIM Input Bias Current | ILIM | $\overline{\text { SHDN }}=\mathrm{V}_{C C}, \mathrm{LIM}=\mathrm{GND}$ or $\mathrm{V}_{\text {CC }}$ | -2 | +2 | $\mu \mathrm{A}$ |
|  |  | $\overline{\text { SHDN }}=$ GND |  | 1 |  |
| PMOS ISOLATION SWITCH (BATT to SW) |  |  |  |  |  |
| PMOS Current Limit |  | $\mathrm{V}_{C C}=2.5 \mathrm{~V}, \mathrm{~V}_{\text {BATT }}=1.5 \mathrm{~V}$ | 0.60 | 1.5 | A |
| PMOS On-Resistance | RDS(ON) | $\mathrm{V}_{\mathrm{CC}}=2.5 \mathrm{~V}, \mathrm{~V}_{\text {BATT }}=1.5 \mathrm{~V}, \mathrm{ISW}=100 \mathrm{~mA}$ |  | 0.4 | $\Omega$ |

Note 1: The MAX1606 requires a supply voltage between +2.4 V and +5.5 V ; however, the input voltage ( $\mathrm{V}_{\text {BATT }}$ ) used to power the inductor can vary from +0.8 V to 5.5 V .
Note 2: Specifications to $-40^{\circ} \mathrm{C}$ are guaranteed by design and not production tested.

Typical Operating Characteristics
$\left(\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{BATT}}=3.6 \mathrm{~V}, \mathrm{~L} 1=10 \mu \mathrm{H}, \overline{\mathrm{SHDN}}=\mathrm{LIM}=\mathrm{V}_{\mathrm{CC}}, \mathrm{VOUT}^{\mathrm{V}}(\mathrm{NOM})=18 \mathrm{~V}\right.$ (Figure 3), $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise noted. )


# $28 V$ Internal Switch LCD Bias Supply with True Shutdown 

## Typical Operating Characteristics (continued)

$\left(\mathrm{VCC}=3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{BATT}}=3.6 \mathrm{~V}, \mathrm{~L} 1=10 \mu \mathrm{H}, \overline{\mathrm{SHDN}}=\mathrm{LIM}=\mathrm{V}_{\mathrm{CC}}, \mathrm{VOUT}_{\mathrm{COM}}\right.$ (NOM $=18 \mathrm{~V}$ (Figure 3), $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise noted. .


EFFICIENCY vs. LOAD CURRENT



EFFICIENCY vs. BATTERY VOLTAGE


EFFICIENCY vs. LOAD CURRENT


SUPPLY CURRENT


EFFICIENCY vs. LOAD CURRENT


PEAK INDUCTOR CURRENT LIMIT vs. SUPPLY VOLTAGE


SUPPLY CURRENT vs. LOAD CURRENT


## 28V Internal Switch LCD Bias Supply with True Shutdown

$\left(\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{BATT}}=3.6 \mathrm{~V}, \mathrm{~L} 1=10 \mu \mathrm{H}, \overline{\mathrm{SHDN}}=\mathrm{LIM}=\mathrm{V}_{\mathrm{CC}}, \mathrm{V}_{\mathrm{OUT}}(\mathrm{NOM})=18 \mathrm{~V}\right.$ (Figure 3), $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise noted. $)$


Pin Description

| PIN | NAME | FUNCTION |
| :---: | :---: | :---: |
| 1 | BATT | Inductor Supply Voltage, 0.8 V to 5.5 V . Internally connected to the source of a P-channel MOSFET used to isolate the output from the input during shutdown. Bypass with a $10 \mu \mathrm{~F}$ or greater capacitor. |
| 2 | FB | Feedback Input. Connect to a resistive divider network between the output and GND to set the output voltage between $\mathrm{V}_{\text {BATT }}$ and 28 V . The feedback threshold is 1.25 V . |
| 3 | Vcc | IC Supply Voltage, 2.4V to 5.5 V . Bypass VCC to GND with a $1 \mu \mathrm{~F}$ or greater capacitor. |
| 4 | GND | Ground |
| 5 | LX | Inductor Switching Connection. Internally connected to the drain of a 28 V N-channel MOSFET. LX is high impedance in shutdown. |
| 6 | LIM | Inductor Current-Limit Selection. Connect LIM to VCC for 500 mA , leave LIM floating for 250 mA , or connect LIM to GND for 125 mA . |
| 7 | $\overline{\text { SHDN }}$ | Active-Low Shutdown Input. A logic low shuts down the device and reduces the supply current to $0.1 \mu \mathrm{~A}$. When shutdown, the MAX1606 isolates the output from the input by turning off the P channel MOSFET between BATT and SW. Connect $\overline{\text { SHDN }}$ to $V_{C C}$ for normal operation. |
| 8 | SW | Isolation Switch Output, Inductor Connection. Internally connected to the drain of a P-channel MOSFET used to isolate the output from the input during shutdown. |

# $28 V$ Internal Switch LCD Bias Supply with True Shutdown 



Figure 1. Functional Diagram


Figure 2. Setting the Peak Inductor Current Limit

## Detailed Description

The MAX1606 step-up DC-DC converter operates from a 2.4 V to 5.5 V supply and converts voltages as low as 0.8 V up to 28 V . The device includes an internal switching MOSFET with a $0.8 \Omega$ on-resistance and selectable current limit (Figure 1) and consumes $160 \mu \mathrm{~A}$ of supply current. During startup, the MAX1606 extends the minimum off-time, limiting initial battery surge current. The MAX1606 uses a P-channel MOSFET to isolate the output from the input during true shutdown mode. This isolation switch also includes short-circuit current limiting,
which protects the inductor and diode during a short-circuit fault.

## Control Scheme

The MAX1606 features a minimum off-time, current-limited control scheme. The duty cycle is governed by a pair of one-shots that set a minimum off-time and a maximum on-time. The switching frequency can be up to 500 kHz and depends upon the load and input voltage. The peak current limit of the internal N -channel MOSFET is pin selectable and may be set at $125 \mathrm{~mA}, 250 \mathrm{~mA}$, or 500 mA (Figure 2).

# 28V Internal Switch LCD Bias Supply with True Shutdown 



Figure 3. Typical Application Circuit

## Setting the Output Voltage (FB)

Adjust the output voltage by connecting a voltagedivider from the output (VOUT) to FB (Figure 3). Select R2 between $10 \mathrm{k} \Omega$ and $200 \mathrm{k} \Omega$. Calculate R1 with the following equation:

$$
\mathrm{R} 1=\mathrm{R} 2\left[\left(\mathrm{~V}_{\mathrm{OUT}} / \mathrm{V}_{\mathrm{FB}}\right)-1\right]
$$

where $\mathrm{V}_{\mathrm{FB}}=1.25 \mathrm{~V}$ and $\mathrm{V}_{\text {OUT }}$ may range from $\mathrm{V}_{\text {BATT }}$ to 28 V . The input bias current of FB has a maximum value of 100 nA , which allows large-value resistors to be used. For less than 1\% error, the current through R2 should be greater than 100 times the feedback input bias current (IFB).

Current-Limit Select Pin (LIM)
The MAX1606 allows a selectable inductor current limit of $125 \mathrm{~mA}, 250 \mathrm{~mA}$, or 500 mA (Figure 2). This allows flexibility in designing for higher current applications or for smaller, compact designs. The lower current limit allows the use of a physically smaller inductor in spacesensitive, low-power applications. Connect LIM to VCC for 500 mA , leave floating for 250 mA , or connect to GND for 125 mA .

## Shutdown ( $\overline{\text { SHDN }}$ )

Pull $\overline{\text { SHDN }}$ low to enter shutdown. During shutdown the supply current drops to $0.1 \mu \mathrm{~A}$, the output is disconnected from the input, and LX enters a high-impedance state. The capacitance and load at the output determine the rate at which Vout decays. SHDN can be pulled as high as 6 V , regardless of the input and output voltages.
With the typical step-up converter circuit, the output remains connected to the input through the inductor and
output rectifier, holding the output voltage to one diode drop below VIN when the converter is shutdown and allowing the output to draw power from the input. The MAX1606 features true shutdown, which uses an internal P-channel MOSFET to disconnect the output from the input when the MAX1606 is shutdown. This eliminates power drawn from the input during shutdown.

Separate/Same Power for Vbatt and Vcc Separate voltage sources can supply the inductor (VBATT) and the IC (VCC). Since the chip bias is provided by a logic supply ( 2.4 V to 5.5 V ), this allows the output power to be sourced directly from low-voltage batteries ( 0.8 V to 5.5 V ). Conversely, VBATT and VCC can also be supplied from one supply if it remains within Vcc's operating limits ( 2.4 V to 5.5 V ).

## Design Procedure

## Inductor Selection

Smaller inductance values typically offer smaller physical size for a given series resistance or saturation current. Circuits using larger inductance values may start up at lower input voltages and exhibit less ripple, but also provide reduced output power. This occurs when the inductance is sufficiently large to prevent the maximum current limit from being reached before the maximum on-time expires. The inductor's saturation current rating should be greater than the peak switching current. However, it is generally acceptable to bias the inductor into saturation by as much as $20 \%$, although this will slightly reduce efficiency.

Picking the Current Limit
The peak LX current limit (ILX(MAX)) required for the application may be calculated from the following equation:

$$
\operatorname{LXX}_{\text {(MAX })} \geq \frac{V_{\text {OUT }} \times \operatorname{IOUT}^{(M A X)}}{V_{\text {BATT(MIN })}}+\frac{\left(V_{\text {OUT }}-V_{\text {BATT(MIN) }}\right) \times \mathrm{t}_{\text {OFF(MIN })}}{2 \times \mathrm{L}}
$$

where $\operatorname{tOFF}(\operatorname{MIN})=0.8 \mu \mathrm{~s}$, and $\mathrm{V}_{\text {BATT }}(\mathrm{MIN})$ is the minimum voltage used to supply the inductor. The set current limit must be greater than this calculated value. Select the appropriate current limit by connecting LIM to Vcc, GND, or leaving it unconnected (see CurrentLimit Select Pin and Figure 2).

Diode Selection The high switching frequency of 500 kHz requires a highspeed rectifier. Schottky diodes, such as the Motorola MBRSO530 or the Nihon EP05Q03L, are recommended. To maintain high efficiency, the average current rating of the Schottky diode should be greater than the peak

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Figure 4. Negative Voltage for LCD Bias
switching current. Choose a reverse breakdown voltage greater than the output voltage.

## Capacitors

For most applications, use a small $1 \mu \mathrm{~F}$ ceramic sur-face-mount output capacitor. For small ceramic capacitors, the output ripple voltage is dominated by the capacitance value. If tantalum or electrolytic capacitors are used, the higher ESR increases the output ripple voltage. Decreasing the ESR reduces the output ripple voltage and the peak-to-peak transient voltage. Surface-mount capacitors are generally preferred because they lack the inductance and resistance of their through-hole equivalents.
Two inputs, VCC and $V_{B A T T}$, require bypass capacitors. Bypass VCC with a $1 \mu \mathrm{~F}$ ceramic capacitor as close to the IC as possible. The BATT input supplies high currents to the inductor and requires local bulk bypassing close to the inductor. A $10 \mu \mathrm{~F}$ low-ESR surface-mount capacitor is sufficient for most applications.
A feed-forward capacitor connected from the output to FB improves stability over a wide range of battery voltages. A 10pF capacitor is sufficient for most applications. Larger values (up to 47pF) may be needed with lower current-limit settings (LIM = GND or open) and low input voltages, or with nonoptimum PC board layouts. Note that increasing CFF may slightly affect load regulation.

PC Board Layout and Grounding Careful printed circuit layout is important for minimizing ground bounce and noise. Keep the MAX1606's ground pin and the ground leads of the input and output capacitors less than $0.2 \mathrm{in}(5 \mathrm{~mm})$ apart. In addition, keep all connections to FB and LX as short as possible.

In particular, external feedback resistors should be as close to FB as possible. To minimize output voltage ripple, and to maximize output power and efficiency, use a ground plane and solder GND directly to the ground plane. Refer to the MAX1606EVKIT evaluation kit for a layout example.

## Applications Information

## Negative Voltage for LCD Bias

The MAX1606 can also generate a negative output by adding a diode-capacitor charge-pump circuit (D1, D2, and C3) to the LX pin as shown in Figure 4. Feedback is still connected to the positive output, which is not loaded, allowing a very small capacitor value at C4. For best stability and lowest ripple, the time constant of the R1-R2 series combination and C4 should be near or less than that of C2 and the effective load resistance. Output load regulation of the negative output is somewhat looser than with the standard positive output circuit, and may rise at very light loads due to coupling through the capacitance of D2. If this is objectionable, reduce the resistance of R1 and R2, while maintaining their ratio, to effectively preload the output with a few hundred microamps. This is why the R1-R2 values shown in Figure 4 are about four-times lower than typical values used for a positive-output design. When loaded, the negative output voltage will be slightly lower (closer to ground by approximately a diode forward voltage) than the inverse of the voltage on C 4 .

## Chip Information

TRANSISTOR COUNT: 3883

## $28 V$ Internal Switch LCD Bias Supply with True Shutdown

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)


NOTES:

1. D\&E DO NOT INCLUDE MOLD FLASH.
2. MOLD FLASH OR PROTRUSIONS NOT TO EXCEED 0.15 MM (.006").
3. CONTROLLING DIMENSION: MILLIMETERS.
4. MEETS JEDEC MO-187C-AA.


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